















ESD

TVS

MOS

LDO

Diode

Sensor

DC-DC

Product Specification

Domestic Part Number	74HC74D / 74HCT74D
Overseas Part Number	74HC74D / 74HCT74D
▶ Equivalent Part Number	74HC74D / 74HCT74D





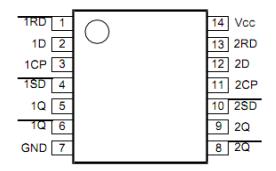
描述

74HC/HCT74是双路上升沿触发的D型触发器。它们具有单独的数据(nD),时钟(nCP), 置数(nSD)和复位(nRD)输入以及互补的nQ和nQ输出。满足从低电平到高电平时钟转换的建立和 保持时间要求的nD输入处的数据存储在触发器中,并出现在nQ输出中。输入内置钳位二极管。这样 就可以使用限流电阻将输入接口连接到超过Vcc的电压。

特点

- 对称输出阻抗
- 低功耗
- 均衡的传输延时

引脚定义



引脚	符号	功 能
1	1RD	异步复位输入(低电平有效)
2	1D	数据输入
3	1CP	时钟输入(低电平到高电平,边缘触发)
4	1SD	异步置数输入(低电平有效)
5	1Q	输出
6	1Q	反相输出
7	GND	地 (0V)
8	2Q	反相输出
9	2Q	输出
10	2SD	异步置数输入(低电平有效)
11	2CP	时钟输入(低电平到高电平,边缘触发)
12	2D	数据输入
13	2RD	异步复位输入(低电平有效)
14	Vcc	电源电压



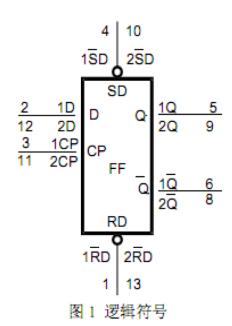
极限参数

参数	符号	极限值	单位
工作电压	V _{CC}	7	V
输入/输出电压	V_{IN} , V_{OUT}	-0.3-Vcc+0.3V	V
单个管脚输出电流	I_{OUT}	±25	mA
Vcc 或 GND 电流	I_{CC}	±50	mA
耗散功率	P _D	500	mW
工作温度	$T_{\mathbf{A}}$	0-70	$^{\circ}$
存储温度	T _S	-65-150	$^{\circ}$
引脚焊接温度	T _W	260, 10s	$^{\circ}$

工作条件

项目		符号	最小值	典型值	最大值	单位
工作电压	V _{CC}		2	5	6	V
输入输出电压	V _{IN} , Vout		0		VCC	V
te) L TL /	Tr	VCC=2.0V	0		1000	ns
输入上升/ 下降时间		VCC=4.5V	0		500	ns
` 年 1月	tf	VCC=6.0V	0		400	ns
工作温度	T _A		0		60	${\mathbb C}$

功能框图



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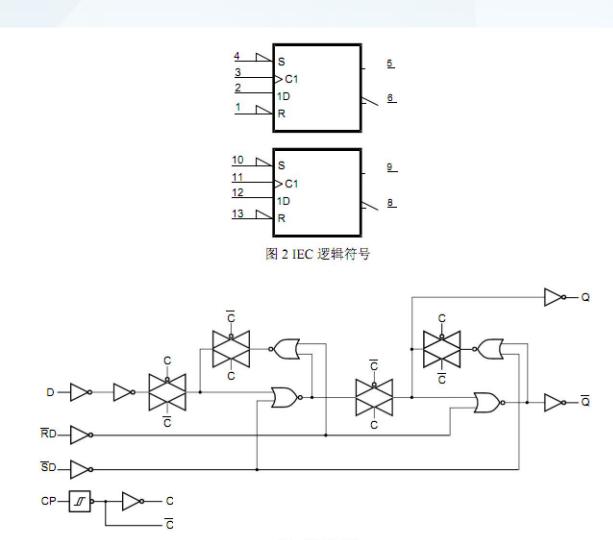
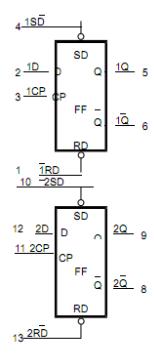


图 3 逻辑框图





功能表

	输	输	出		
nSD	nRD	nRD nCP		nQ	nQ
L	Н	X	X	Н	L
Н	L	X	X	L	Н
L	L	X	X	Н	Н

	输	输	出		
nSD	nRD	nQ_{n+1}	$n \bar{Q}_{n+1}$		
Н	Н	1	L	L	Н
H	H	1	H	Н	L

注: H=高电平; L=低电平; X=无关;

↑=低电平到高电平转换; Qn+1=下一个低电平到高电平CP转换后状态。

电学特性

直流电学特性: TA=25℃

参数名称	符号	38	最小	典型	最大	单位	
古山 平松)			V _{CC} =2.0V	1.5	1.2	_	V
高电平输入 电压	V_{IH}		V _{CC} =4.5V	3.15	2.4		V
电压			Vcc=6.0V	4.2	3.2	_	V
(八山 豆炒)			V _{cc} =2.0V	_	0.8	0.5	V
低电平输入	$V_{\rm IL}$		Vcc=4.5V	_	2.1	1.35	V
电压			V _{CC} =6.0V	_	2.8	1.8	V
高电平输出	V_{OH}	V _I =V _{III} 或V _{IL}	I ₀ =-4.0mA; V _{CC} =4.5V		4.32		V
电压	V ОН	V _I =V _{IH} X,V _{IL}	I _O =-5.2mA; V _{CC} =6.0V	5.34	5.81	_	V
低电平输出	V_{OL}	V _I =V _{III} 或V _{IL}	I ₀ =4.0mA; V _{CC} =4.5V	-	0.15	0.33	V
电压	V OL	VI-VIHEX VIL	I ₀ =5.2mA; V _{CC} =6.0V	_	0.16	0.33	V
输入漏电流	$I_{\rm I}$	_	$V_I = V_{CC}$ 或GND; $V_{CC} = 6.0V$			±1.0	uA
静态电流	I _{CC}	V _I =V _{CC}	_	_	40	uA	
输入电容	C_{I}		_		3.5	_	pF



交流电学特性: TA=25℃

参数名称	符号		测试条件	最小	典型	默大	单位
			74HC74	•		•	
			V _{cc} =2.0V	_	47	220	ns
nCP到nQ, nQ		见图6[1]	Vcc=4.5V	_	17	44	ns
的传输延时	t _{pd}	元国0.	Vcc=5.0V: CL=15pF	_	14	_	ns
			Vcc=6.0V	_	14	37	ns
			Vcc=2.0V	_	50	250	ns
nSD∯lnQ, nQ		见图7[1]	Vcc=4.5V	_	18	50	ns
的传输延时	t _{pd}	光图/**	Vcc=5.0V: CL=15pF	_	15	_	ns
			V _{CC} =6.0V	_	14	43	ns
			Vcc=2.0V	_	52	250	ns
nRD到nQ,nQ		见图7 ^[1]	Vcc=4.5V	_	19	50	ns
的传输延时	t _{pd}	处国/**	Vcc=5.0V; CL=15pF	_	16	_	ns
			Vcc=6.0V	_	15	43	ns
_			Vcc=2.0V	_	19	95	ns
nQ, nQ	tı	见图6 ^[2]	Vcc=4.5V	_	7	19	ns
转换时间			Vcc=6.0V	_	6	16	ns
		tw 见图6	Vcc=2.0V	100	19	_	ns
CP脉宽	t _W		Vcc=4.5V	20	7	_	ns
			Vcc=6.0V	17	6	_	ns
		tw 见图7	Vcc=2.0V	100	19	_	ns
nSD, nRD脉宽	tw		Vcc=4.5V	20	7	_	ns
			Vcc=6.0V	17	6	_	ns
			Vcc=2.0V	40	3	_	ns
nSD, nRD	trec	见图7	Vcc=4.5V	8	1	_	ns
恢复时间			Vcc=6.0V	7	1	_	ns
n Zil en			Vcc=2.0V	75	6	_	ns
nD到nCP	t _{su}	见图6	Vcc=4.5V	15	2	_	ns
设置时间			Vcc=6.0V	13	2	_	ns
n til en			V _{CC} =2.0V	3	-6	_	ns
nD到nCP	th	见图6	Vcc=4.5V	3	-2	_	ns
保持时间			Vcc=6.0V	3	-2	_	ns
			Vcc=2.0V	4.8	23	_	MHz
- on E. L. keletr	e	pri Del »	Vcc=4.5V	24	69	_	MHz
nCP最大频率	f_{max}	见图6	Vcc=5.0V: CL=15pF	_	76	_	MHz
			Vcc=6.0V	28	82	_	MHz
功耗电容	C_{PD}		0pF; f=1MHz; =GND~V _{CC} ^[3]	_	24	_	pF

注:

[2] t_t与t_{THL}和t_{TLH}相同。

^[1] tpd与tpLH和tpHL相同。



交流测试线路图

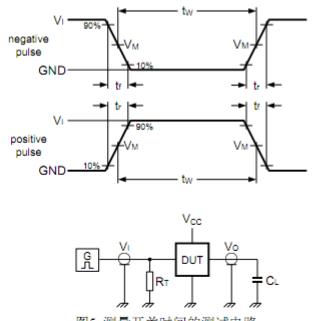


图5 测量开关时间的测试电路

测试电路的定义:

C_L=负载电容,包括探针、夹子上的电容 R_T=终端电阻须与信号发生器的输出阻抗 Z_o匹配

交流测试波形

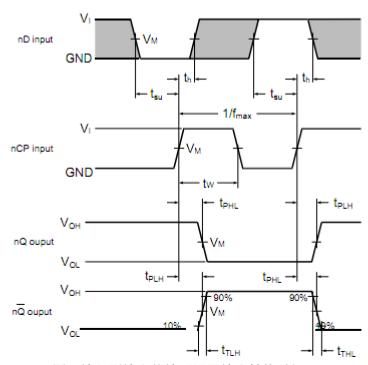


图6 输入到输出传输延迟及输出转换时间



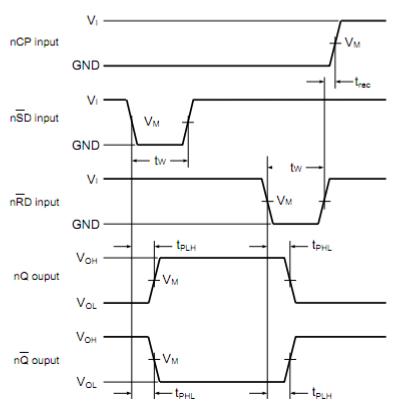


图7 设置和复位传输延时,脉冲宽度和恢复时间

测试点

类型	輸入	輸出
文 堡	V_{M}	V_{M}
74HC74	0.5×V _{CC}	$0.5 \times V_{CC}$

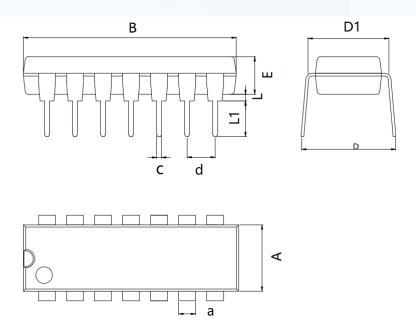
测试数据

类型	綸	入	负	载	测试
火生	V_{I}	tro tr	C_L	$\mathbf{R}_{\mathbf{L}}$	-009 IPA
74HC74	V_{cc}	6.0ns	15pF, 50pF	1kΩ	t _{PLH} , t _{PHL}



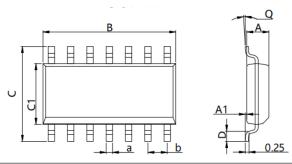
封装信息

DIP14



Dimensions In Millimeters(DIP14)											
Symbol:	Α	В	D	D1	Е	L	L1	а	С	d	
Min:	6.10	18.94	8.40	7.42	3.10	0.50	3.00	1.50	0.40	2.54 BSC	
Max:	6.68	19.56	9.00	7.82	3.55	0.70	3.60	1.55	0.50	2.54 BSC	

SOP14



Dimensions In Millimeters(SOP14)											
Symbol:	Α	A1	В	С	C1	D	Q	а	b		
Min:	1.35	0.05	8.55	5.80	3.80	0.40	0°	0.35	1,27 BSC		
Max:	1.55	0.20	8.75	6.20	4.00	0.80	8°	0.45	1.27 BSC		



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